



使用LNK605芯片设计的12V 300mA LED 驱动电源

2010年5月11日
TH (PI-Shenzhen)

PI-LED-S03

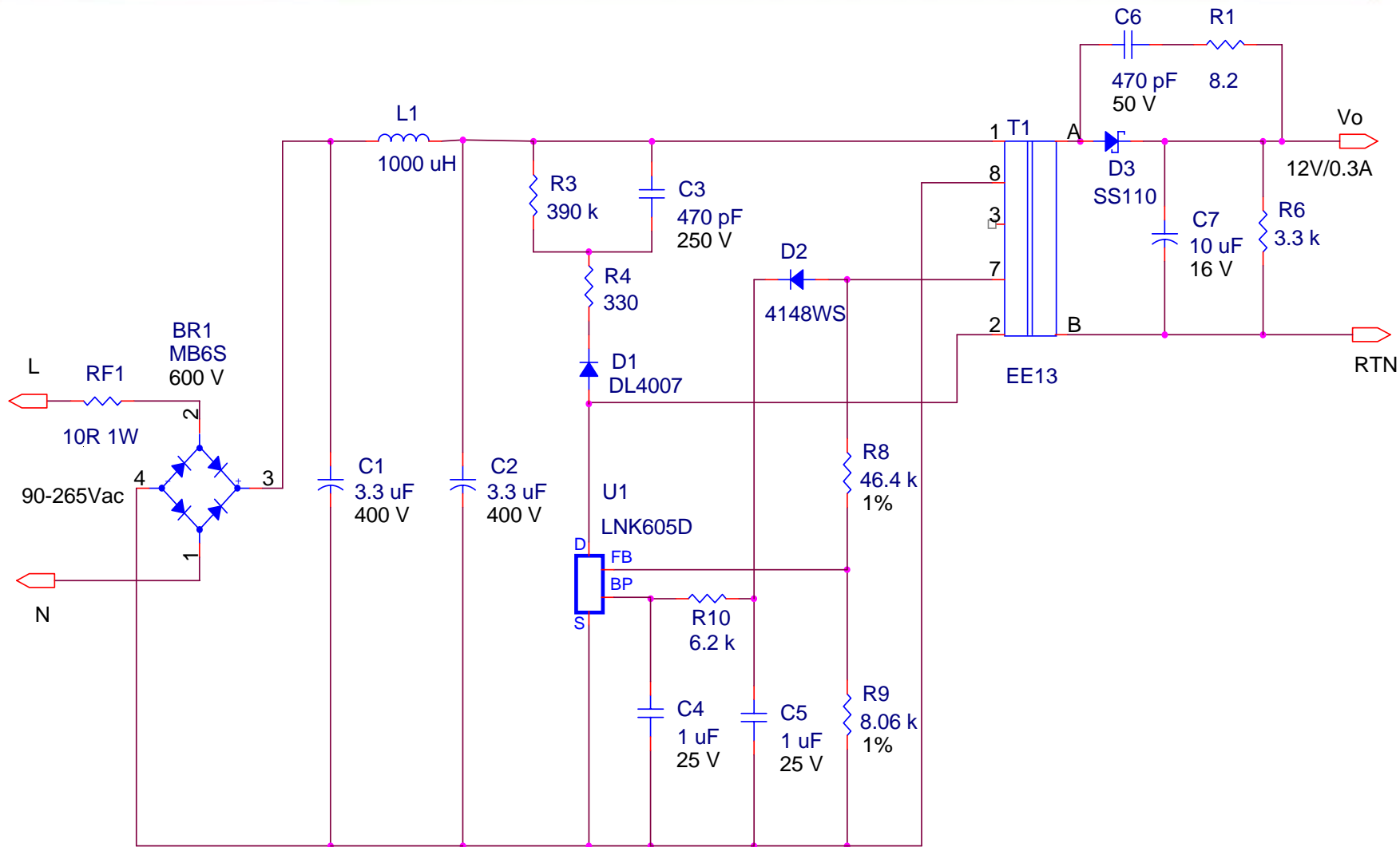
1. 主要功能及特点

1. 无 Y 电容设计
2. 初级侧精准的恒流控制, 无需光耦和次级控制线路
3. 集成MOS管, 外围零件数目少, 能放入GU10壳内
4. 高效率, 115V/230V输入时效率大于76%
5. 宽电压范围输入 (90~265Vac)
6. 内部集成过温度保护功能, ~142°C
7. 短启动时间, <200mS@90Vac

2. 产品规格

描述	符号	最小值	典型值	最大值	单位	附加信息/测试条件
输入						
输入电压	V_{IN}	90		265	Vac	零/火线, 无中线
空载损耗	W			0.1		265V输入
输出						
输出电压	V_{out}	11	12.0	13	V	
输出电流	I_{out}		0.3		A	
总输出功率						
持续输出功率	P_{out}		3.6		W	总功率
峰值输出功率					W	
传导电磁干扰		6			dB	
环境温度	T_{amb}	0		70	C	空气自然对流

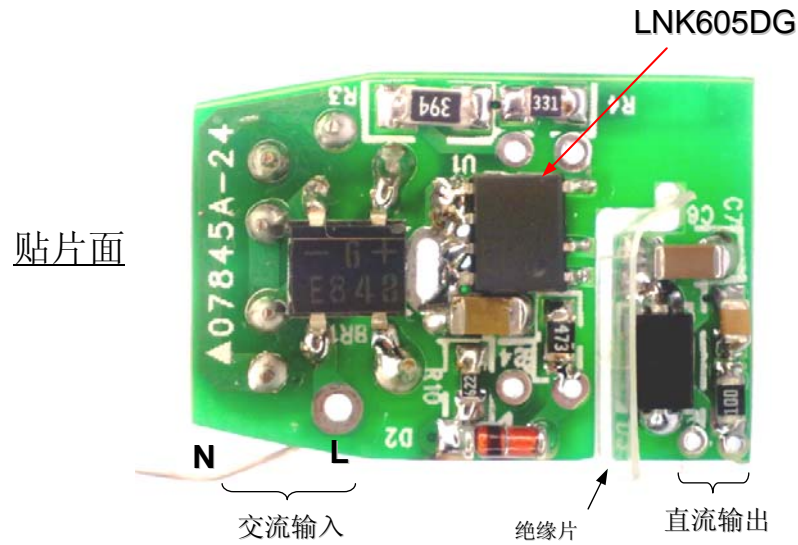
3. 线路图



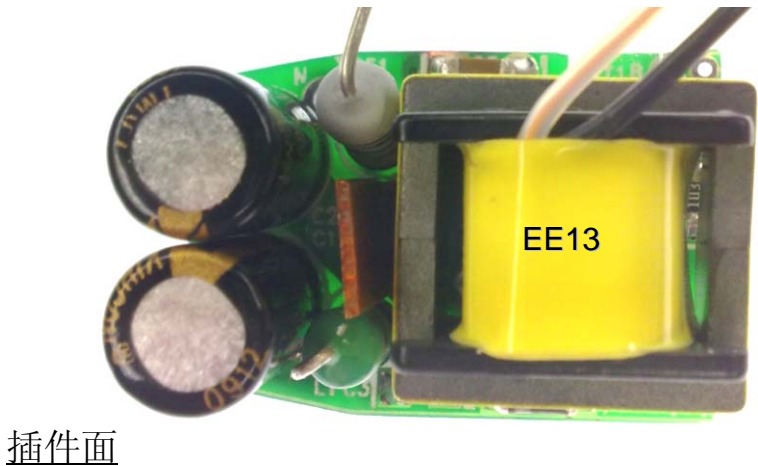
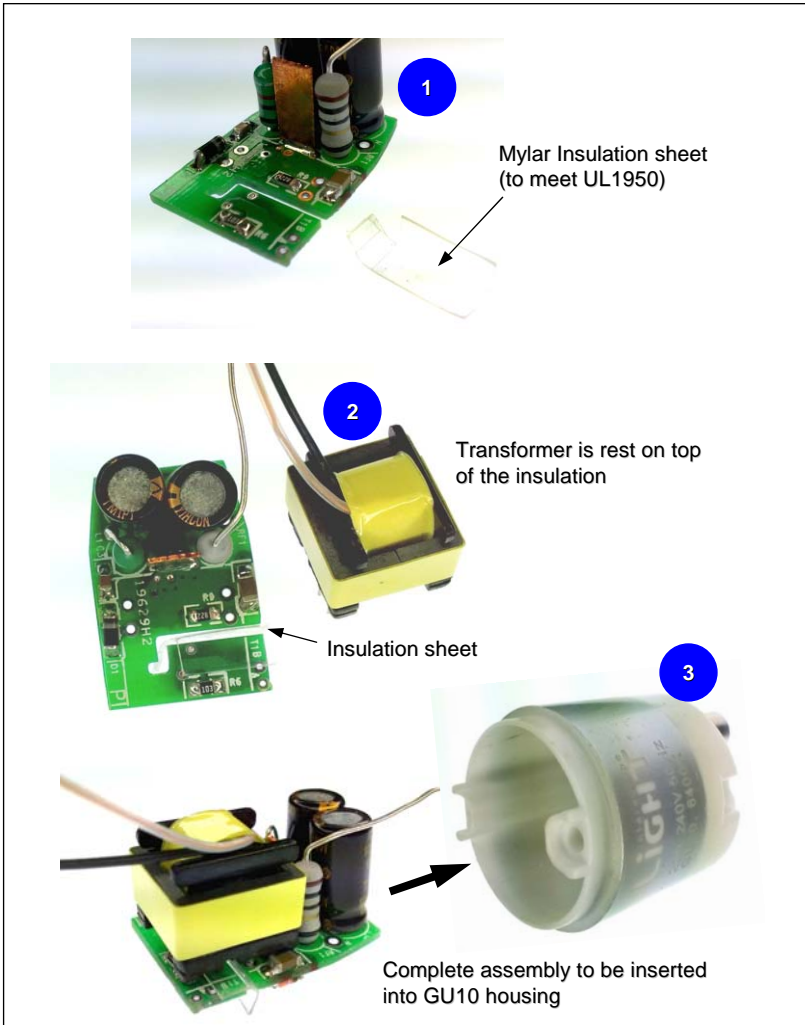
4. 零件清单

编码	数量	零件位置	零件值	具体描述
1	1	BR1	MB6S	600 V, 0.5 A, Bridge Rectifier, SMD, DFS, SOIC-4
2	2	C1 C2	3.3 uF	3.3 uF, 400 V, Electrolytic, (10 x 12.5)
3	1	C3	470 pF	470 pF, 250 V, Ceramic, X7R, 0805
4	2	C4 C5	1 uF	1 uF, 25 V, Ceramic, X7R, 0805
5	1	C6	470 pF	470 pF 50 V, Ceramic, X7R, 0603
6	1	C7	10 uF	10 uF, 16 V, Ceramic, X7R, SMD 1206
7	1	D1	DL4007	1000 V, 1 A, Rectifier, Glass Passivated, DO-213AA (MELF)
8	1	D2	4148WS	75 V, 0.15 A, Fast Switching, 4 ns, MELF
9	1	D3	SS110	100 V, 1 A, Schottky, DO-214AC (SMA)
10	1	L1	1000 uH	1000 uH, 80 mA, 34.7 Ohm, Axial Ferrite Inductor
11	1	R1	8.2	8.2 R, 1%, 1/16 W, Thick Film, 0603
12	1	R3	390 k	390 k, 5%, 1/4 W, Thick Film, 1206
13	1	R4	330	330 R, 5%, 1/8 W, Thick Film, 0805
14	1	R6	3.3 k	3.3 k, 5%, 1/8 W, Thick Film, 0805
15	1	R8	46.4 k	46.4 k, 1%, 1/8 W, Thick Film, 0805
16	1	R9	8.06 k	8.06 k, 1%, 1/16 W, Thick Film, 0603
17	1	R10	6.2 k	6.2 k, 5%, 1/8 W, Thick Film, 0805
18	1	RF1	10R 1W	10 R, 1 W, Fusible/Flame Proof Wire Wound
19	1	T1	EE13	EE13, Horizontal , 8 pins
20	1	U1	LNK605D	LinkSwitch-II, LNK605DG, SMD-8B

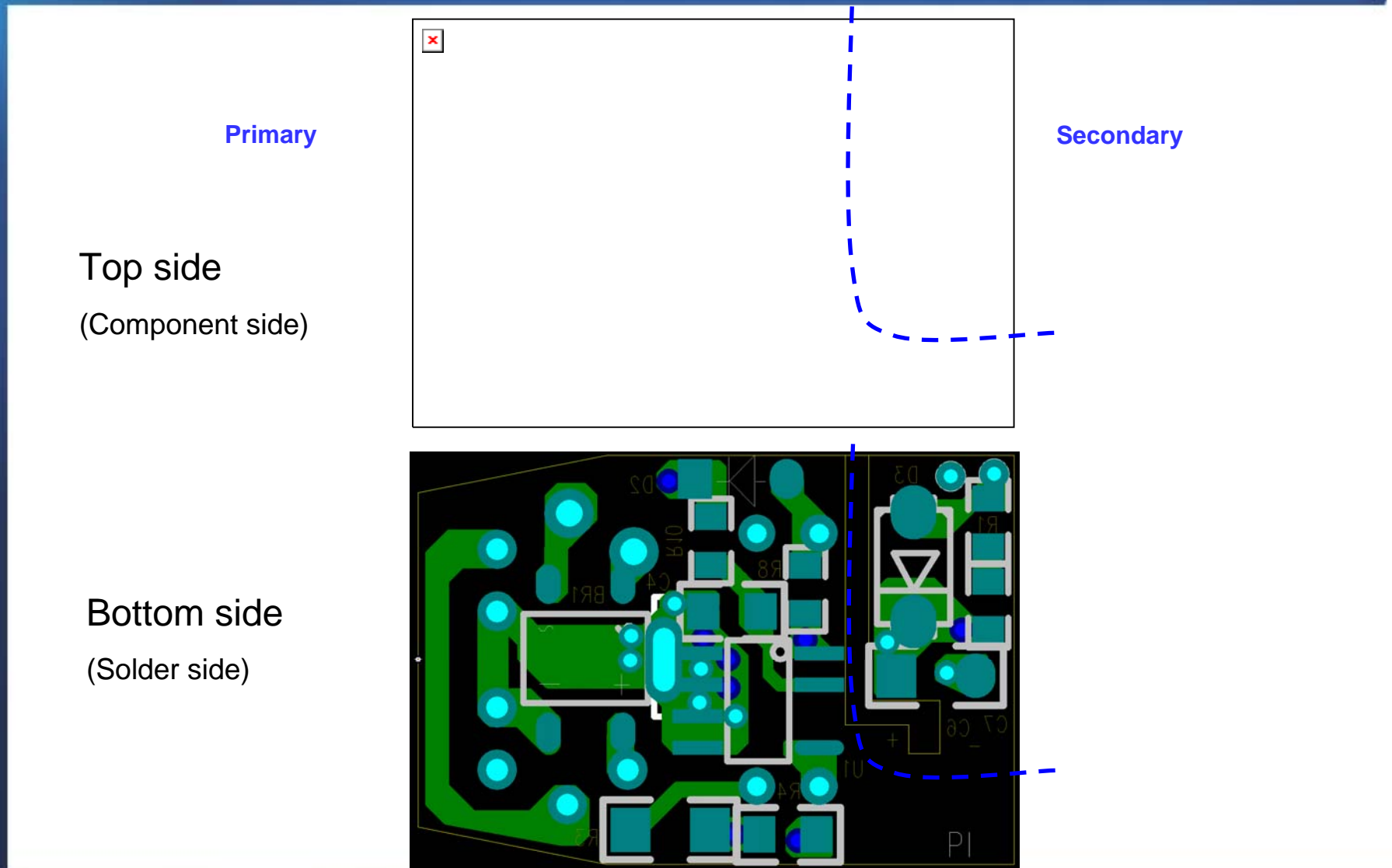
5.工程样品外观图



Assembly Details

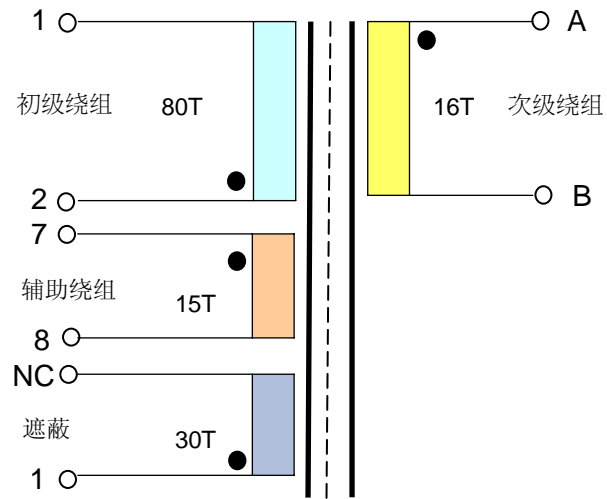


6. 布板图

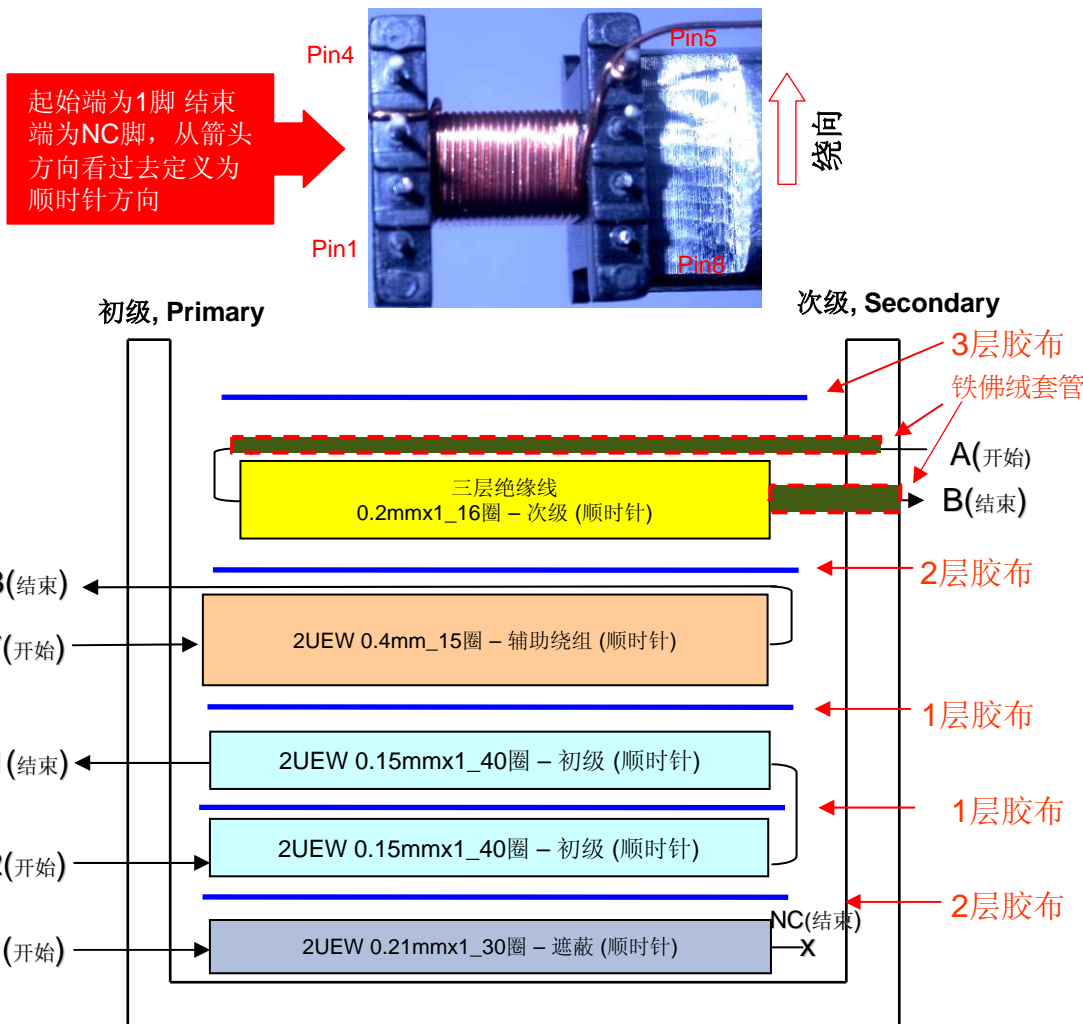


7. 变压器规格

示意图



绕组结构图...



电气规格:

1. 初级感量 (Lp) = 1100 uH ± 7% @80KHz 0.4V
2. 初级漏感 <30uH @80KHz 0.4V
3. 抗电强度 = 3KV, 50/60Hz, 1Min

材料:

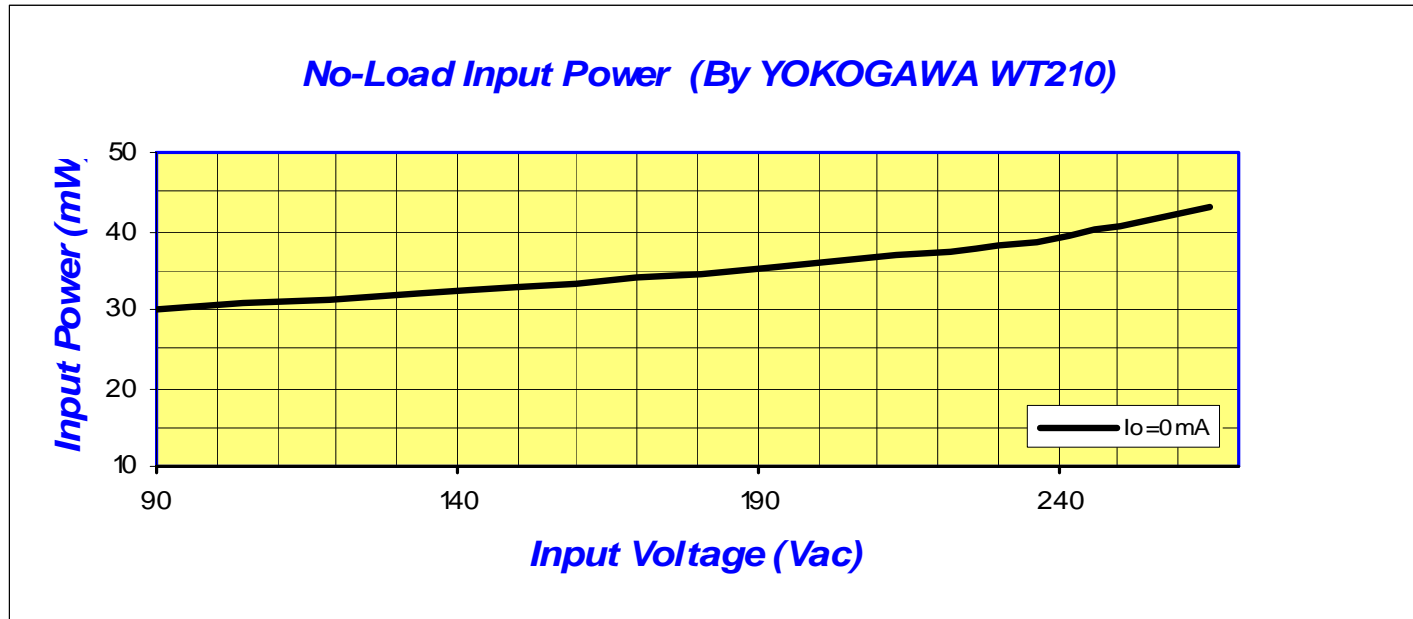
1. 磁芯: 特殊EE13 (铁氧体 TDK PC40 或其他等效)
2. 骨架: 卧式 (4+4 脚).
3. 绕线 (初级和辅助绕组): 类型 2-UEW
4. 绕线 (次级绕组): 三层绝缘线
5. 绕组间绝缘胶布 :3M1298 或其他等效

组装:

1. 组立后需要泡凡立水

8. 电气性能

空载损耗图



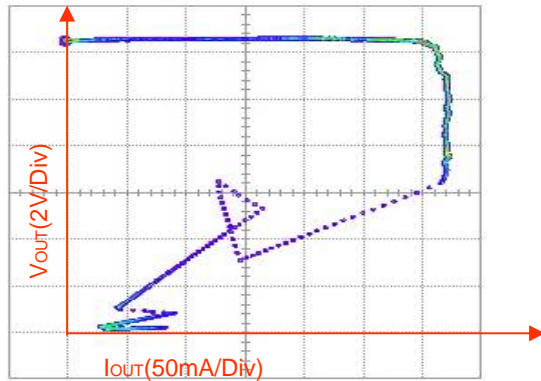
效率

测试条件:满载

输入	90V	115V	150V	200V	230V	265V
效率	75.50%	77.00%	77.50%	77.10%	76.50%	75%

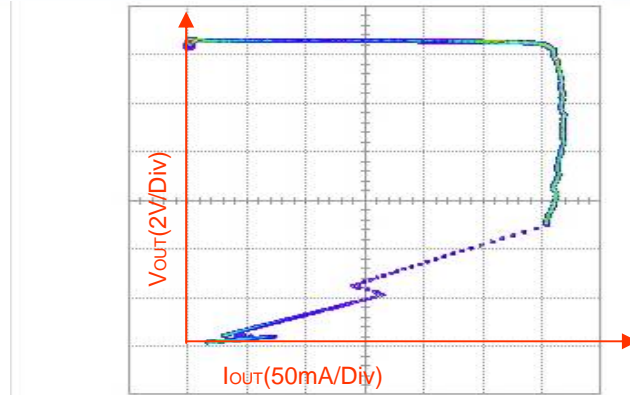
9. 输出电压电流曲线图

工程报告 (使用LNK605DG芯片设计的 12V 300mA LED 驱动电源, PI-LED-03)



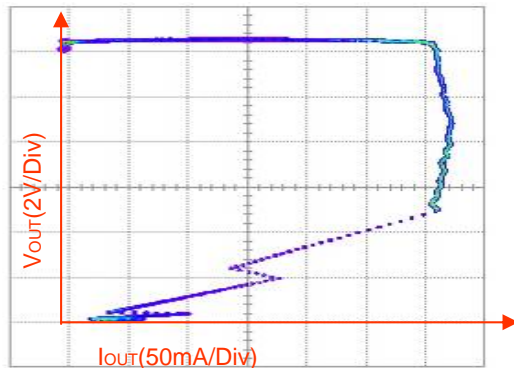
XY X:C3 Y:C4
2.00 V/div
50.0 mA/div
785 #

输入电压90Vac



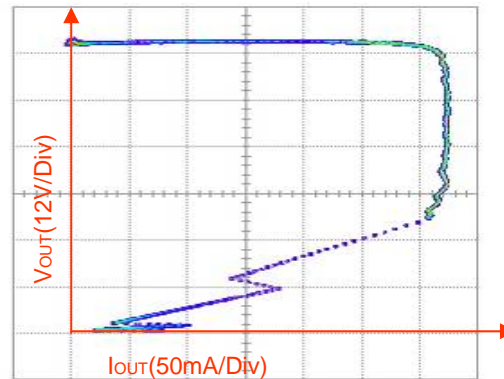
XY X:C3 Y:C4
2.00 V/div
50.0 mA/div
747 #

输入电压120Vac



XY X:C3 Y:C4
2.00 V/div
50.0 mA/div
738 #

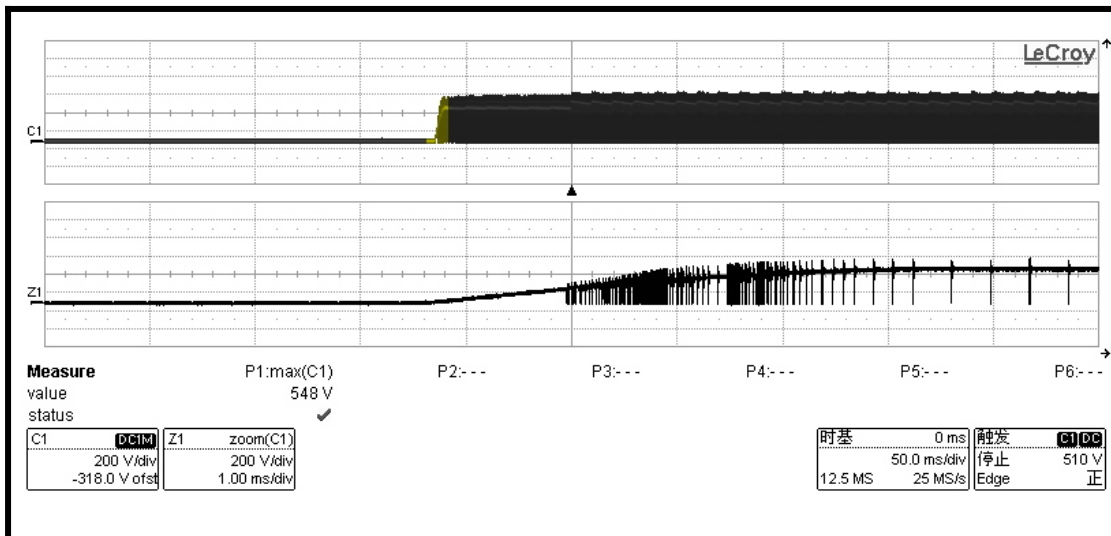
输入电压230Vac



XY X:C3 Y:C4
2.00 V/div
50.0 mA/div
705 #

输入电压264Vac

10. 漏极电压应力



测试条件:
265VAC电压输入
输出电流0.3A

结果: 通过
最大应力电压=**548V**

LNK-II 最大允许数据值表 — — — — — (LNK605DG)

Absolute Maximum Ratings⁽¹⁾

DRAIN Voltage	-0.3 V to 700 V	Lead Temperature ⁽²⁾	260 °C
DRAIN Peak Current: LNK603/613	320 (480) mA ⁽³⁾	Notes:	
LNK604/614	400 (600) mA ⁽³⁾	1. All voltages referenced to SOURCE, T _a = 25 °C.	
LNK605/615	504 (750) mA ⁽³⁾	2. Duration not to exceed 2 msec.	
LNK606/616	654 (960) mA ⁽³⁾	3. 1/16 in. from case for 5 seconds.	
Peak Negative Pulsed Drain Current	-100 mA ⁽³⁾	4. The higher peak DRAIN current is allowed while the DRAIN voltage is simultaneously less than 400 V.	
Feedback Voltage	-0.3 V to 9 V	5. Maximum ratings specified may be applied, one at a time without causing permanent damage to the product.	
Feedback Current	100 mA	Exposure to Absolute Maximum ratings for extended periods of time may affect product reliability.	
BYPASS Pin Voltage	-0.3 V to 9 V		
Storage Temperature	-65 °C to 150 °C		
Operating Junction Temperature	-40 °C to 150 °C		

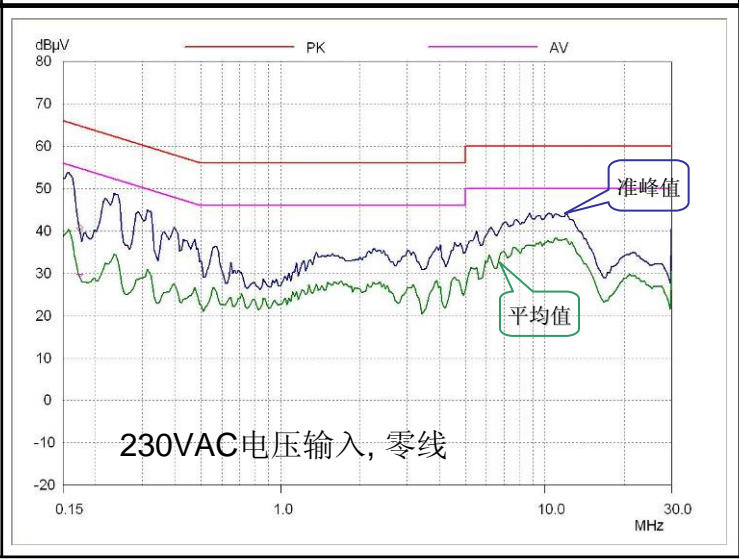
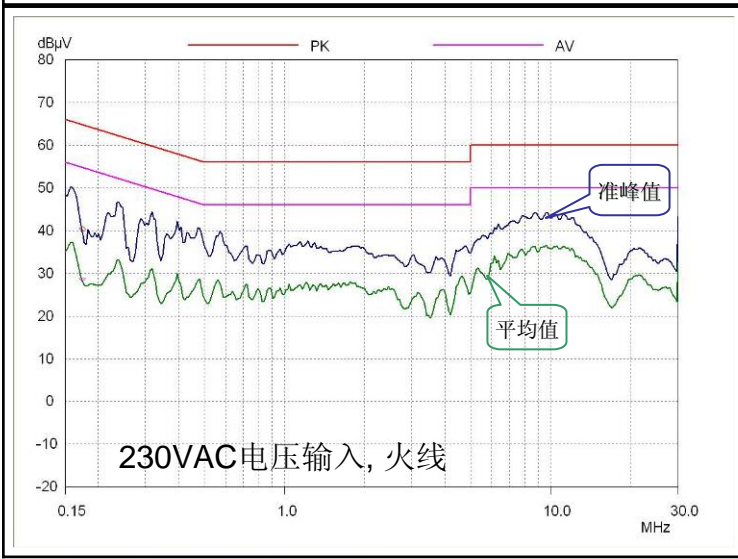
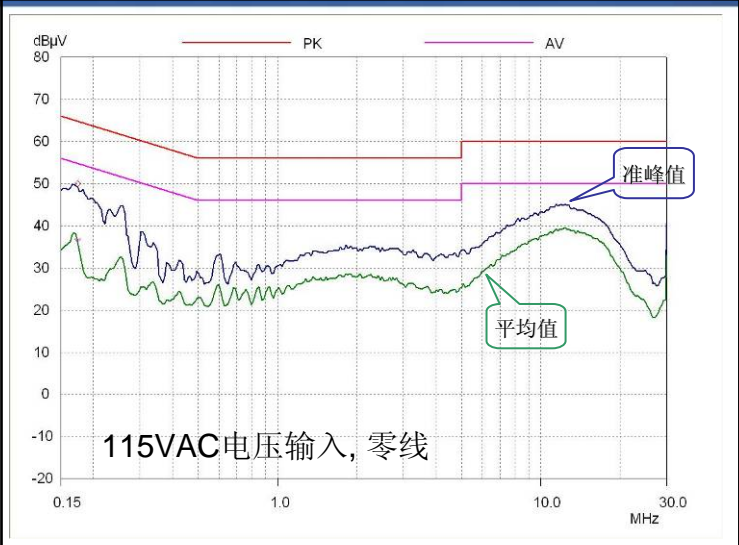
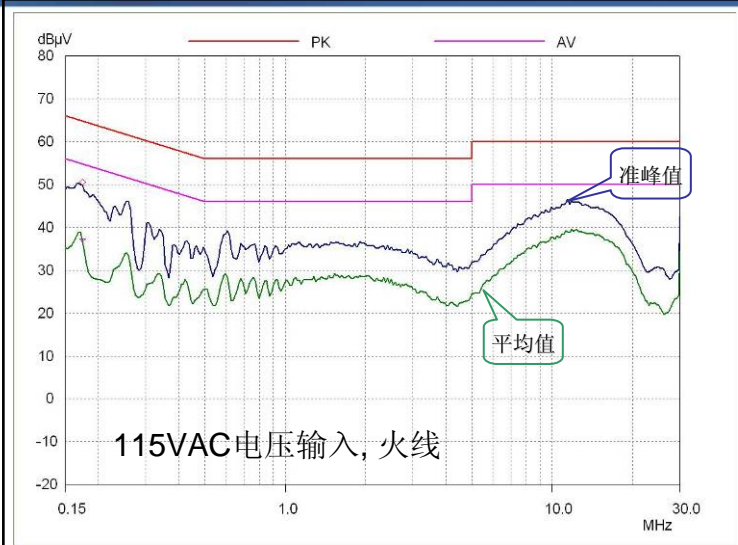
Thermal Impedance

Thermal Impedance: P or G Package:	
(θ _{JA}) ⁽⁴⁾	70 °C/W ⁽³⁾ ; 60 °C/W ⁽³⁾
(θ _{JD}) ⁽⁴⁾	11 °C/W
D Package:	
(θ _{JA}) ⁽⁴⁾	100 °C/W ⁽³⁾ ; 80 °C/W ⁽³⁾
(θ _{JD}) ⁽⁴⁾	30 °C/W

- Notes:
- Measured on pin 8 (SOURCE) close to plastic interface.
 - Soldered to 0.36 sq. in. (232 mm²), 2 oz. (610 g/m²) copper clad.
 - Soldered to 1 sq. in. (645 mm²), 2 oz. (610 g/m²) copper clad.

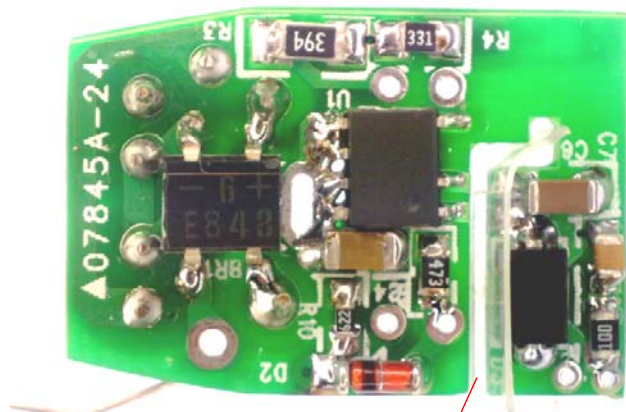
11.传导电磁干扰测试 (准峰值和平均值)

工程报告 (使用LNK605DG芯片设计的 12V 300mA LED 驱动电源, PI-LED-03)



12. 静电测试结果

ESD(KV)	PASS OR FAILURE
10KV	PASS
11KV	PASS
12KV	PASS
13KV	PASS
14KV	PASS

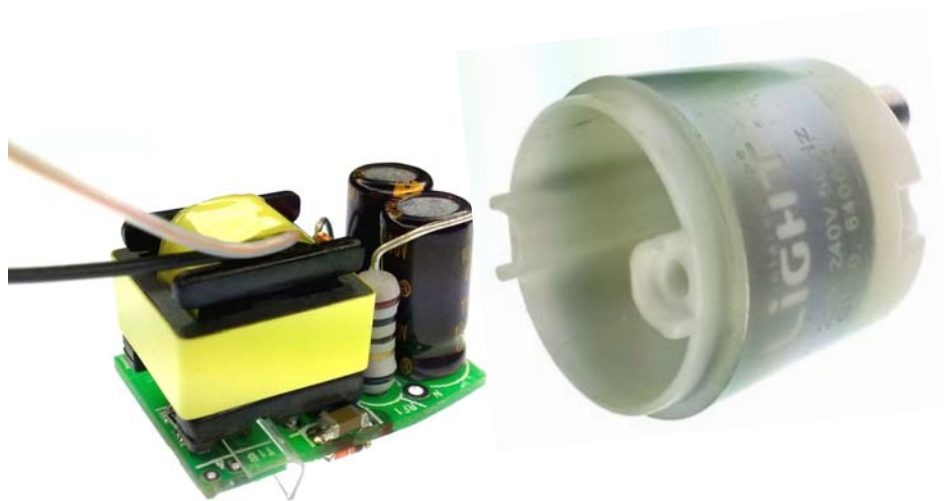


备注: 绝缘片放入初次之间有起到静电ESD保护作用

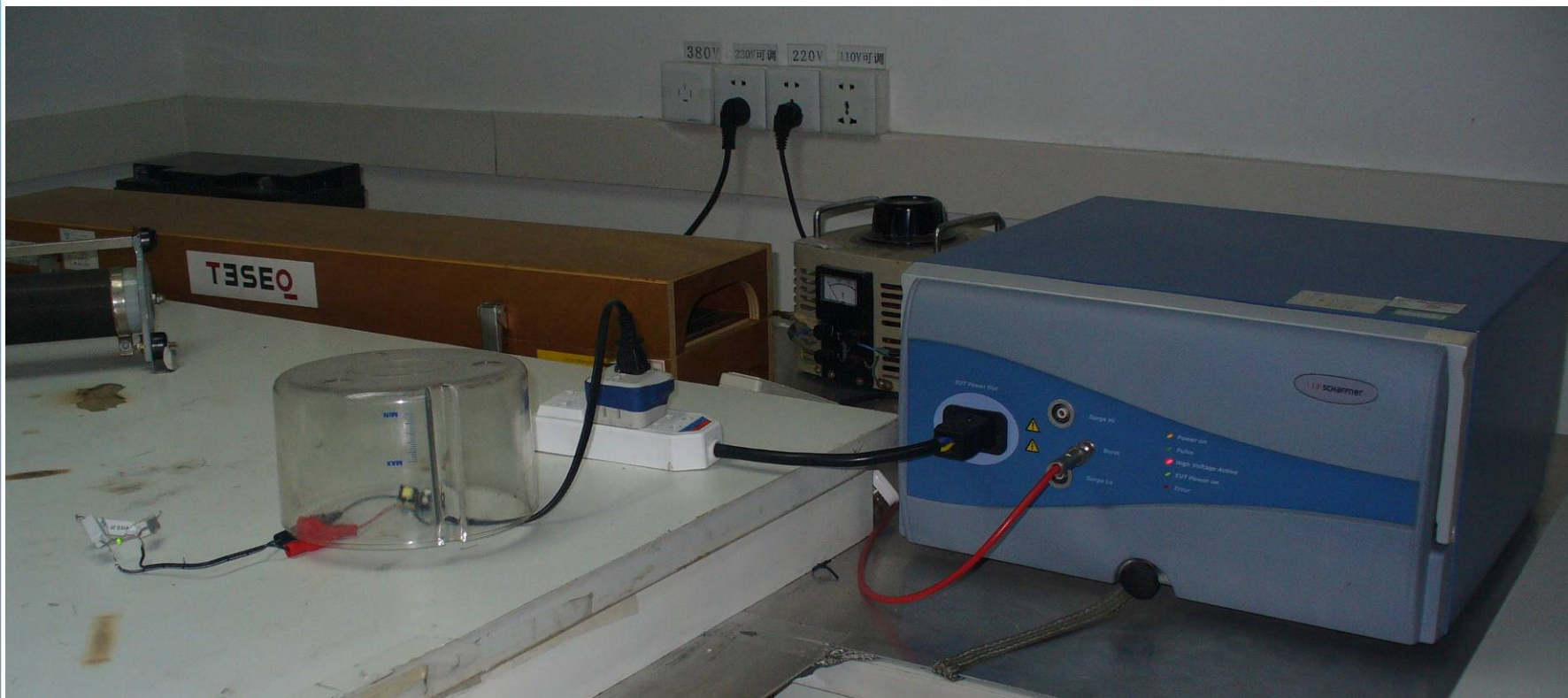
13. 温度上升测试结果

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	Input:90Vac Amb:70°C	Input:264Vac Amb:70°C
Device	Temperature	Temperature
U1(LNK605DG)	112	115
T1(winding)	96.1	97
T1(core)	101.1	102.5
D2(SS110)	94.7	94.9
C1(3.3uF/400V)	92.9	91
C2(3.3uF/400V)	93.3	91.6

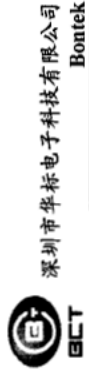


14. 雷击应力测试状态



14.A 雷击应力测试结果 (通过2KV)

工程报告 (使用LNK605DG芯片设计的 12V 300mA LED 驱动电源, PI-LED-03)



Surge Immunity Test Data

编号: TR-4-E-005 Rev:A0

Standard IEC 61000-4-5 IEC 61000-4-5 Result: PASS / FAIL

Applicant: PI EUT: M/N: GU10

Repetition: 5 times per test Interval: 60 seconds Criteria: B C



Ambient Condition: 25 °C 55 %RH 101 kPa

Input Voltage: 230 V 50 Hz

Operation Mode: FULL LOAD

Line:	<input checked="" type="checkbox"/> AC Mains		<input type="checkbox"/> DC Supply		<input type="checkbox"/> Signal Line:		Telephone Line				
	Volt	Phase	500V	+	1.0kV	-	2.0kV	+	3.0kV	+	4.0kV
L-N	0°		PASS	PASS	PASS	PASS	PASS	PASS	PASS	PASS	PASS
	90°		PASS	PASS	PASS	PASS	PASS	PASS	PASS	PASS	PASS
	180°		PASS	PASS	PASS	PASS	PASS	PASS	PASS	PASS	PASS
	270°		PASS	PASS	PASS	PASS	PASS	PASS	PASS	PASS	PASS
L-PE	0°										
	90°										
	180°										
N-PE	0°										
	90°										
	180°										
L-N-PE	0°										
	90°										
	180°										
Telephone Line	L1-L2										
	L1-PE										
	L2-PE										

Note: Test Equipment: SCHAFFNER Model: MODULA6150

Date: 2010.4.30 Test:  Approve: 

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Important note

Although this board is designed to satisfy safety isolation requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an isolation transformer to provide the AC input to the prototype board.

The products and applications illustrated herein (including circuits external to the products and transformer construction) may be covered by one or more U.S. and foreign patents or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at www.powerint.com.